

## Dual N-channel Enhancement Mode Power MOSFET

### Features

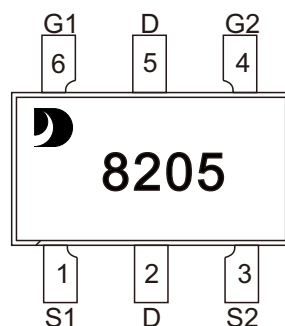
- 20V, 5A  
 $R_{DS(ON)} < 26m\Omega @ V_{GS}=4.5V$   
 $R_{DS(ON)} < 26m\Omega @ V_{GS}=2.5V$
- Advanced Trench Technology
- Provide Excellent  $R_{DS(ON)}$  and Low Gate Charge
- Lead free product is acquired



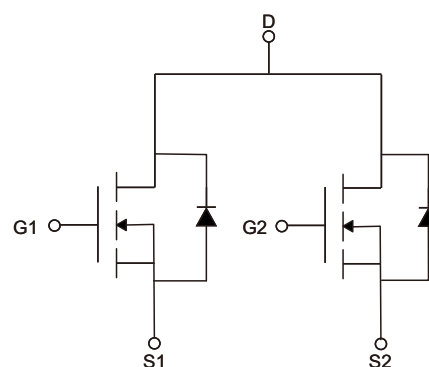
SOT26(Dual)

### Application

- Load Switch
- PWM Application
- Power management



Marking and pin Assignment



Schematic Diagram

### Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Max	Units
$V_{DSS}$	Drain-Source Voltage	20	V
$V_{GSS}$	Gate-Source Voltage	$\pm 10$	V
$I_D$	Continuous Drain Current	$T_A=25^\circ\text{C}$	5
		$T_A=100^\circ\text{C}$	3.2
$I_{DM}$	Pulsed Drain Current <sup>Note1</sup>	20	A
$P_D$	Power Dissipation	$T_A=25^\circ\text{C}$	1.5
$R_{\theta JA}$	Thermal Resistance , Junction to Ambient	83.3	$^\circ\text{C}/\text{W}$
$T_J, T_{STG}$	Operating and Storage Temperature Range	-50 to +150	$^\circ\text{C}$

Note: 1. Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature



## Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Drain-Source Breakdown Voltage	$B_{VDSS}$	$V_{GS}=0V, I_D=250\mu A$	20	21		V
Static Drain-Source On-Resistance	$R_{DS(on)(FT)}$	$V_{GS}=4.5V, I_D=4.0A$		20	25	m $\Omega$
		$V_{GS}=2.5V, I_D=3.0A$		26	36	m $\Omega$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	0.45	0.7	1.1	V
Gate-to-Source Leakage Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$			1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 10V$			$\pm 100$	nA
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V$ $f=1.0MHz$		800		pF
Output Capacitance	$C_{oss}$			155		pF
Reverse Transfer Capacitance	$C_{rss}$			125		pF
Total Gate Charge	$Q_g$	$V_{DS}=10V, V_{GS}=4.5V$ $I_D=3A$		11		nC
Gate-Source Charge	$Q_{gs}$			2.3		nC
Gate-Drain("Miller") Charge	$Q_{gd}$			2.5		nC
Turn-on Delay Time	$t_{d(on)}$	$V_{DS}=10V, V_{GS}=4.5V$ $I_D=3A, R_{GEN}=3\Omega$		18		ns
Turn-on Rise Time	$t_r$			5		ns
Turn-off Delay Time	$t_{d(off)}$			43		ns
Turn-off Fall Time	$t_f$			20		ns



### Typical Electrical and Thermal Characteristics

Fig.1 Capacitance vs.Drain-Source Voltage

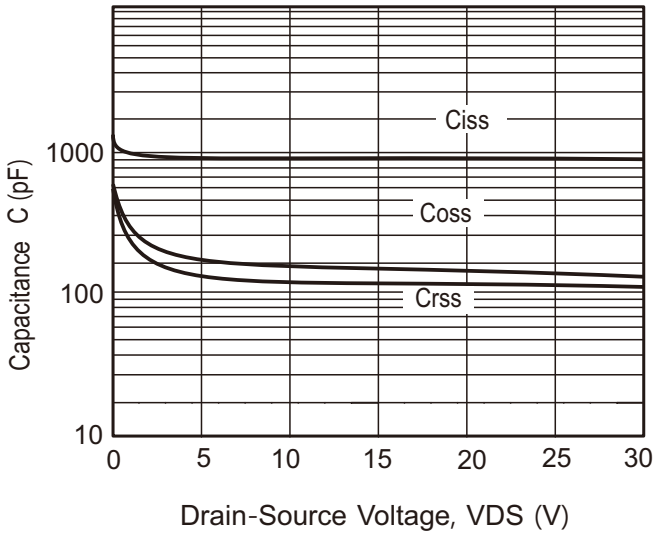


Fig.2 Gate Charge Vs.Gate-Source Voltage

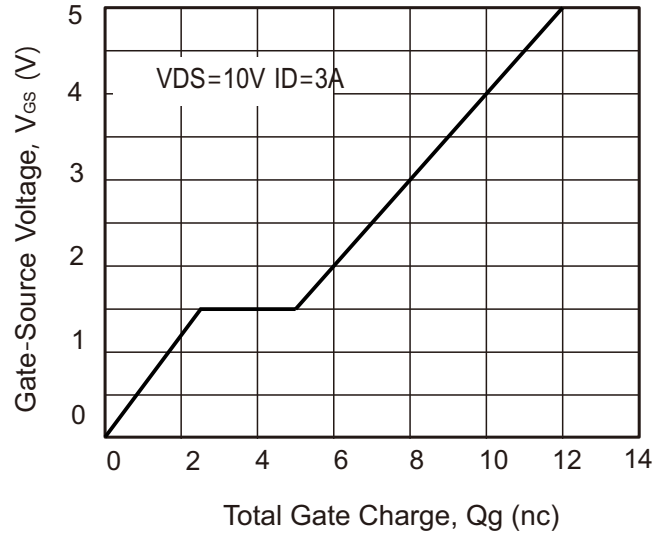


Fig 3 Output Characteristics

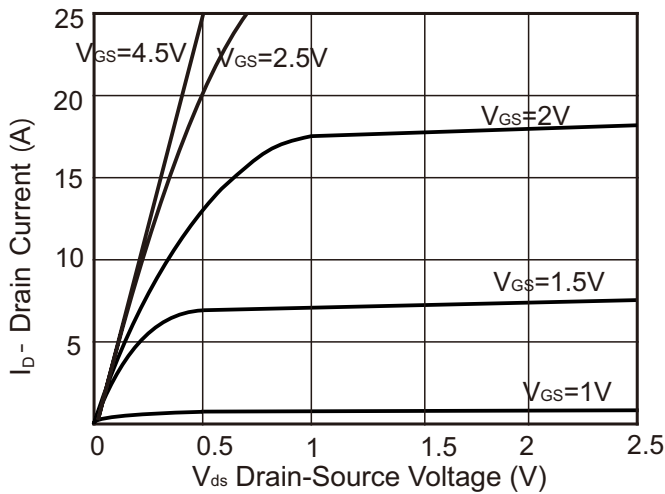


Fig 4 Drain-Source On-Resistance

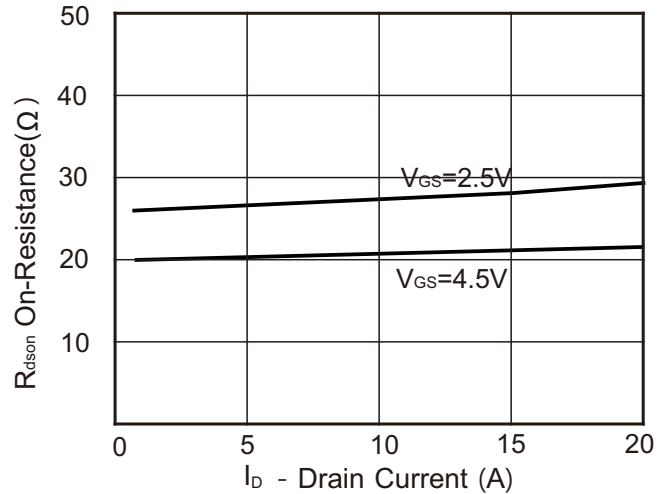


Fig 5 Transfer Characteristics

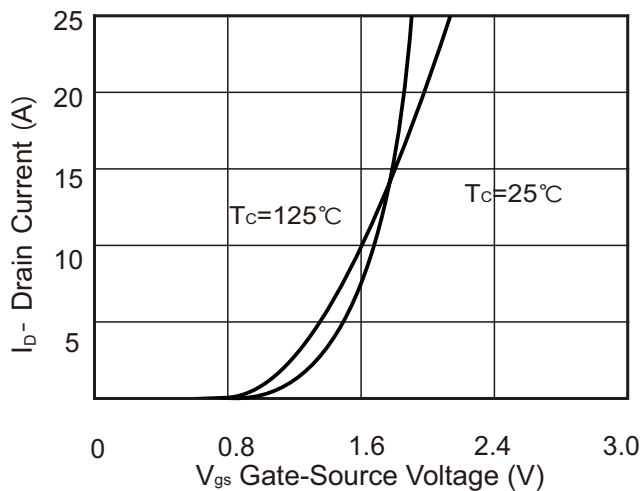


Fig 6 Source- Drain Diode Forward

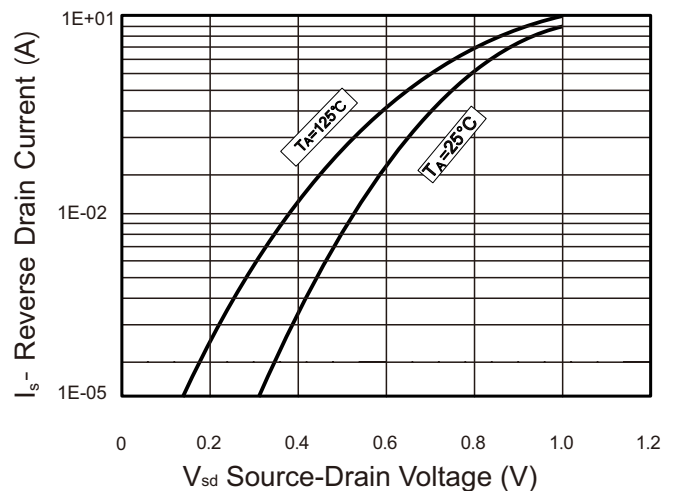




Fig 7 Safe Operation Area

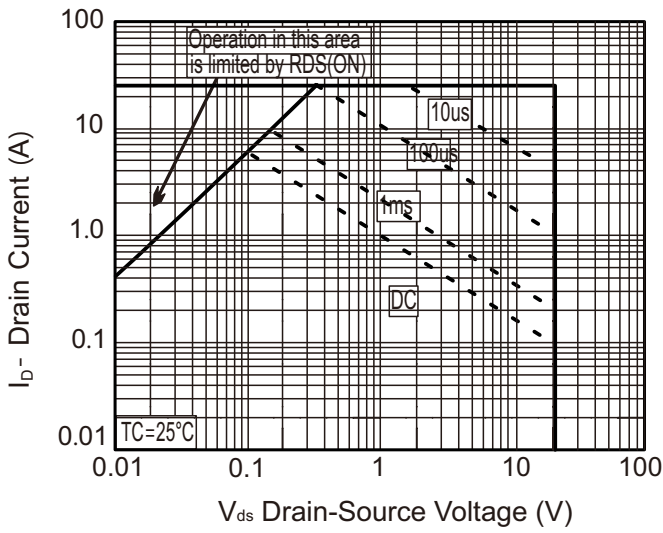


Fig 8 Normalized Breakdown Voltage vs . Junction Temperature

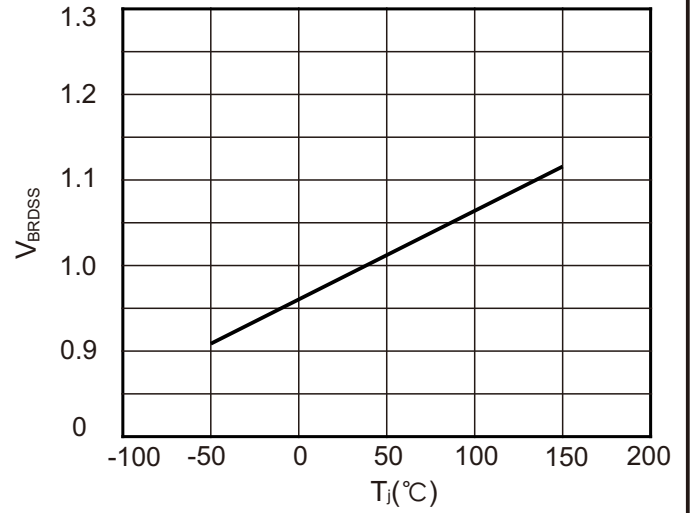


Fig 9 Normalized on Resistance vs . Junction Temperature

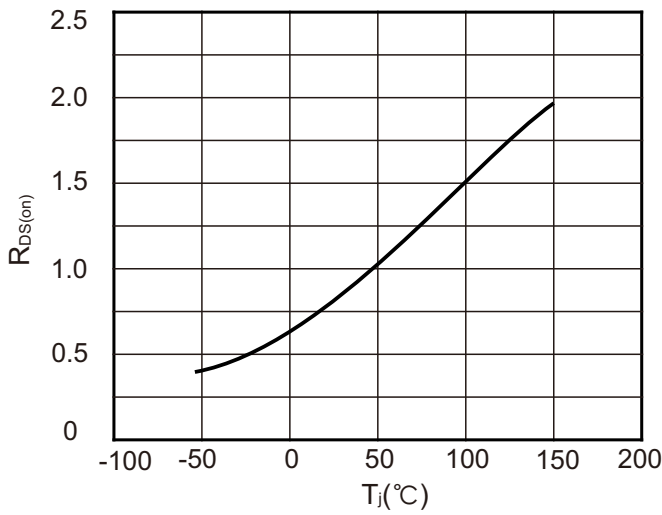
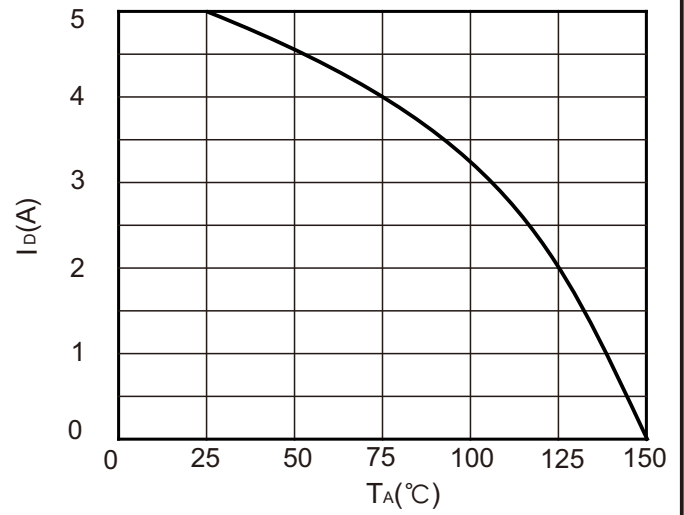


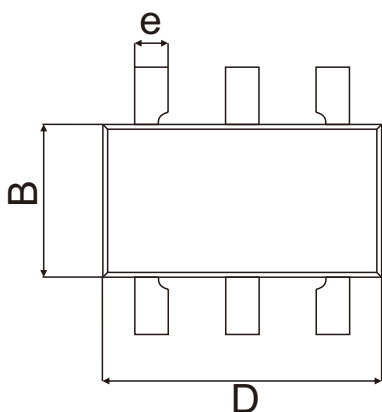
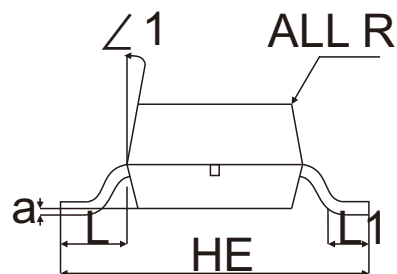
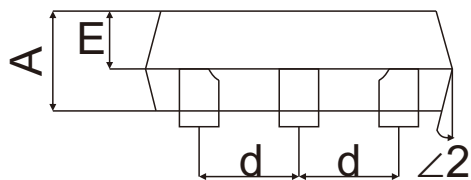
Fig 9 Maximum Continuous Drain Current vs . Ambient Temperature





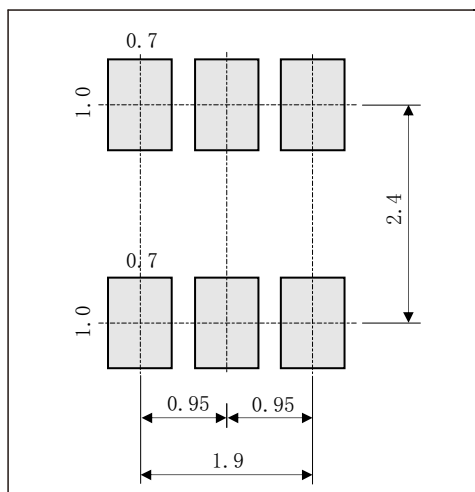
**PACKAGE OUTLINE**

Plastic surface mounted package; 6 leads



Unit		A	B	C	HE	D	d	E	e	L	L1	a	R	∠1	∠2
mm	max	1.05	1.80	0.20	2.90	3.12	1.00	0.65	0.40	0.70	0.60	0.2 (ref)	R0.1 (ref)	12°	10°
	typ	0.95	1.60	0.15	2.80	2.92	0.95	0.55	0.35	0.60	/				
	min	0.85	1.40	0.10	2.70	2.72	0.90	0.45	0.30	0.50	0.20				
mil	max	41	71	8	114	123	39	26	16	28	24	8 (ref)	R4 (ref)		
	typ	37	63	6	110	115	37	22	14	24	/				
	min	33	55	4	106	107	35	18	12	20	8				

**The recommended mounting pad size**



**Marking**

Type number	Marking code
NM8205	8205



文件履历表

序号	制/修订日期	生效日期	版次	修订内容	变更原因	制/修订人	备注
01	2022.4.21	2022.4.21	Rev 1.1	初版制定	/	陶倩	

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [MOSFET](#) category:*

*Click to view products by [Jingdao](#) manufacturer:*

Other Similar products are found below :

[MCH3443-TL-E](#) [MCH6422-TL-E](#) [FDPF9N50NZ](#) [NTNS3A92PZT5G](#) [IRFD120](#) [JANTX2N5237](#) [2N7000](#) [2SK2464-TL-E](#) [AOD464](#) [2SJ277-DL-E](#) [2SK2267\(Q\)](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#) [MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [SSM6J414TU,LF\(T](#) [751625C](#) [IRS2092STRPBF-EL](#) [IPS70R2K0CEAKMA1](#) [BSF024N03LT3 G](#) [PSMN4R2-30MLD](#) [TK31J60W5,S1VQ\(O](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [P85W28HP2F-7071](#) [DMN1053UCP4-7](#) [NTE2384](#) [NTE2969](#) [NTE6400A](#) [DMC2700UDMQ-7](#) [DMN2080UCB4-7](#) [DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [SSM6P54TU,LF](#) [DMP22D4UFO-7B](#) [IPS60R3K4CEAKMA1](#) [DMN1006UCA6-7](#) [DMN16M9UCA6-7](#) [STF5N65M6](#) [IRF40H233XTMA1](#) [IPSA70R950CEAKMA1](#) [IPSA70R2K0CEAKMA1](#) [STU5N65M6](#) [C3M0021120D](#) [DMN6022SSD-13](#)